Unit: mm

### TOSHIBA PHOTOCOUPLER PHOTO RELAY

## **TLP199D**

# MEASUREMENT INSTRUMENTS LOGIC IC TESTERS / MEMORY TESTERS BOARD TESTERS / SCANNERS

The TOSHIBA TLP199D consist of a gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a plastic SOP package. Its characteristics include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency mearsurement instruments.

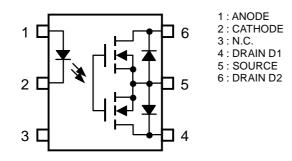
### **FEATURES**

• 6 pin SOP (2.54SOP6) : 2.1 mm high, 2.54 mm pitch

• 1-Form-A

Peak Off-State Voltage : 200 V (min)
 Trigger LED Current : 3 mA (max)
 On-State Current : 50 mA (max)
 On-State Resistance : 50 ohm (max)
 Output Capacitance : 20 pF (max)
 Isolation Voltage : 1500 Vrms (min)

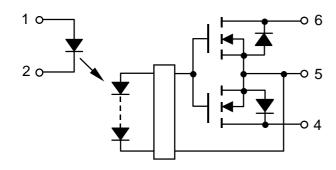
### **PIN CONFIGURATION (TOL VIEW)**



# JEDEC EIAJ TOSHIBA 11-7C1

Weight: 0.13 g

### **SCHEMATIC**



### **MAXIMUM RATINGS (Ta = 25°C)**

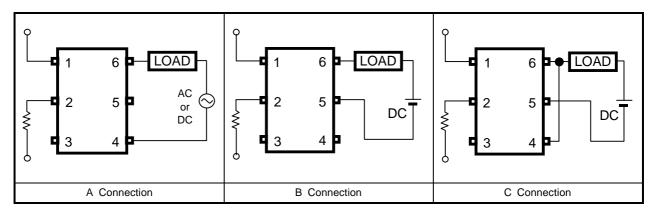
	CHARACTERISTI	SYMBOL	RATING	UNIT		
	Forward Current	l <sub>F</sub>	50	mA		
۵	Forward Current Derating (Ta	ΔI <sub>F</sub> /°C	-0.5	mA/°C		
쁘	Reverse Voltage		$V_{R}$	5	V	
	Junction Temperature		Tj	125	°C	
	Off-State Output Terminal Vo	oltage	V <sub>OFF</sub>	200	V	
		A Connection		50	mA	
œ	On-State Current	B Connection	I <sub>ON</sub>	50		
CTO		C Connection		100		
DETECTOR	On-State Current Derating (Ta ≧ 25°C)	A Connection	Δl <sub>ON</sub> /°C	-0.5	mA/°C	
		B Connection		-0.5		
	(1a = 25 0)	C Connection		-1.0		
	Junction Temperature		Tj	125	°C	
Storage Temperature Range			T <sub>stg</sub>	-55~125	°C	
Operating Temperature Range			T <sub>opr</sub>	-40~85	°C	
Lead Soldering Temperature (10 s)			T <sub>sol</sub>	260	°C	
Isolation Voltage (AC, 1 minute, R.H. $\leq$ 60%) (NOTE1)			BVS	Vrms		

(NOTE1) : Device considered a two-terminal device : LED side pins are shorted together, and DETECTOR side pins are shorted together.

### **RECOMMENDED OPERATING CONDITIONS**

CHARACTERISTIC	SYMBOL	Min	Тур.	Max	UNIT
Supply Voltage	$V_{DD}$	_	_	160	V
Forward Current	I <sub>F</sub>	5	7.5	15	mA
On-State Current	I <sub>ON</sub>	_	_	50	mA
Operating Temperature	T <sub>opr</sub>	-20	_	60	°C

### **CIRCUIT CONNECTIONS**



### INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
	Forward Voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
ED	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V		_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
TECTOR	Off-State Current	l <sub>OFF</sub>	V <sub>OFF</sub> = 160 V	_	_	1	nA
DETE	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	15	20	pF

### **COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARAC	CTERISTIC	SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
Trigger LED Current		I <sub>FT</sub>	I <sub>ON</sub> = 50 mA	_	1	3	mA
Return LED Current		I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	_	_	mA
On-State Resistance	A Connection		I <sub>ON</sub> = 50 mA, I <sub>F</sub> = 5 mA	_	40	50	
	B Connection	R <sub>ON</sub>	I <sub>ON</sub> = 50 mA, I <sub>F</sub> = 5 mA	_	30	40	Ω
	C Connection		$I_{ON} = 100 \text{ mA}, I_F = 5 \text{ mA}$		15		

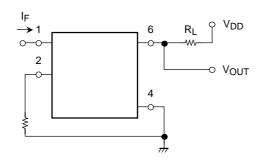
### **ISOLATION CHARACTERISTICS (Ta = 25°C)**

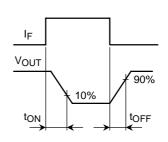
CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
Capacitance Input to Output	CS	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≦ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 minute	1500	_	_	Vrms
Isolation Voltage		AC, 1 second (in oil)	_	3000	_	VIIIIS
		DC, 1 minute (in oil)	_	3000	_	Vdc

### **SWITCHING CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
Turn-on Time	t <sub>ON</sub>	$R_L = 200 \Omega$ (NOTE 2)	_	_	0.5	ms
Turn-off Time	t <sub>OFF</sub>	$V_{DD} = 10 \text{ V}, I_{F} = 5 \text{ mA}$	_	_	0.2	1113

(NOTE 2): SWITCHING TIME TEST CIRCUIT





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